

# BCR10FM-12LC

600V - 10A - Triac

Medium Power Use

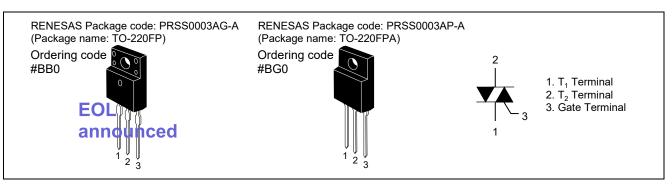
## Features

- I<sub>T (RMS)</sub> : 10 A
- V<sub>DRM</sub> : 600 V
- Tj: 150°C
- IFGTI, IRGTI, IRGT III: 50 mA

#### • Insulated Type

- Planar Passivation Type
- Viso: 2000 V

# Outline



# Application

Low inrush current AC load.

### **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage <sup>Note1</sup>	Vdrm	600	V
Non-repetitive peak off-state voltage <sup>Note1</sup>	VDSM	700	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	IT (RMS)	10	Α	Commercial frequency, sine full wave
				360° conduction, Tc = 82°C
Surge on-state current	Itsm	60	Α	60 Hz sinewave 1 full cycle, peak value,
				non-repetitive
I <sup>2</sup> t for fusion	l <sup>2</sup> t	15	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave
				60 Hz, surge on-state current
Peak gate power dissipation	P <sub>GM</sub>	5	W	
Average gate power dissipation	Pg (AV)	0.5	W	
Peak gate voltage	$V_{\text{GM}}$	10	V	
Peak gate current	lgм	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Isolation voltage Note6	Viso	2000	V	Ta=25°C, AC 1 minute,
				T <sub>1</sub> • T <sub>2</sub> • G terminal to case

Notes: 1. Gate open.

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### **Electrical Characteristics**

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cu	urrent	IDRM	_		2.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
On-state voltage		V <sub>TM</sub>	_	_	1.8	V	Tc = 25°C, I <sub>TM</sub> = 15 A, instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	Ι	VFGTI	_	_	1.5	V	Tj = 25°C, $V_D$ = 6 V, $R_L$ = 6 Ω,
	II	V <sub>RGTI</sub>			1.5	V	R <sub>G</sub> = 330 Ω
	III	Vrgtiii	_		1.5	V	
Gate trigger curent <sup>Note2</sup>	Ι	IFGTI			50	mA	Tj = 25°C, V <sub>D</sub> = 6 V, R <sub>L</sub> = 6 Ω,
	II	IRGTI			50	mA	R <sub>G</sub> = 330 Ω
	III	IRGTIII	_	_	50	mA	
Gate non-trigger voltage		V <sub>GD</sub>	0.2	_	_	V	Tj = 125°C, V <sub>D</sub> = 1/2 V <sub>DRM</sub>
Thermal resistance		Rth (j-c)			4.6	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of rise of off-sta commutation voltage <sup>Note4</sup>	ate	(dv/dt)c	10	_	_	V/µs	Tj = 125°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. The contact thermal resistance Rth(c-f) in case of greasing is 0.5°C /W.

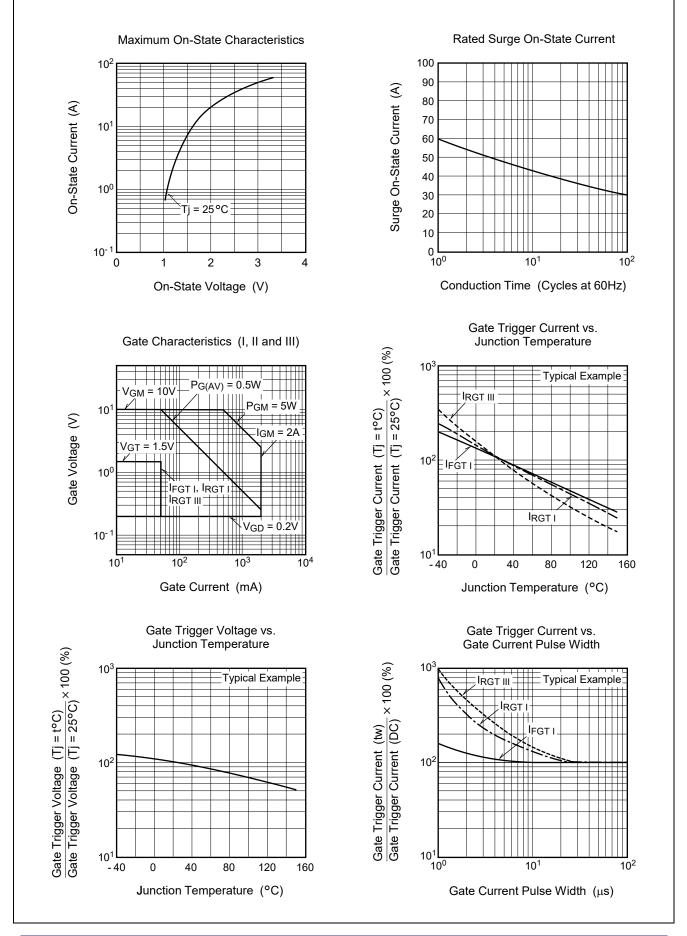
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

5. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

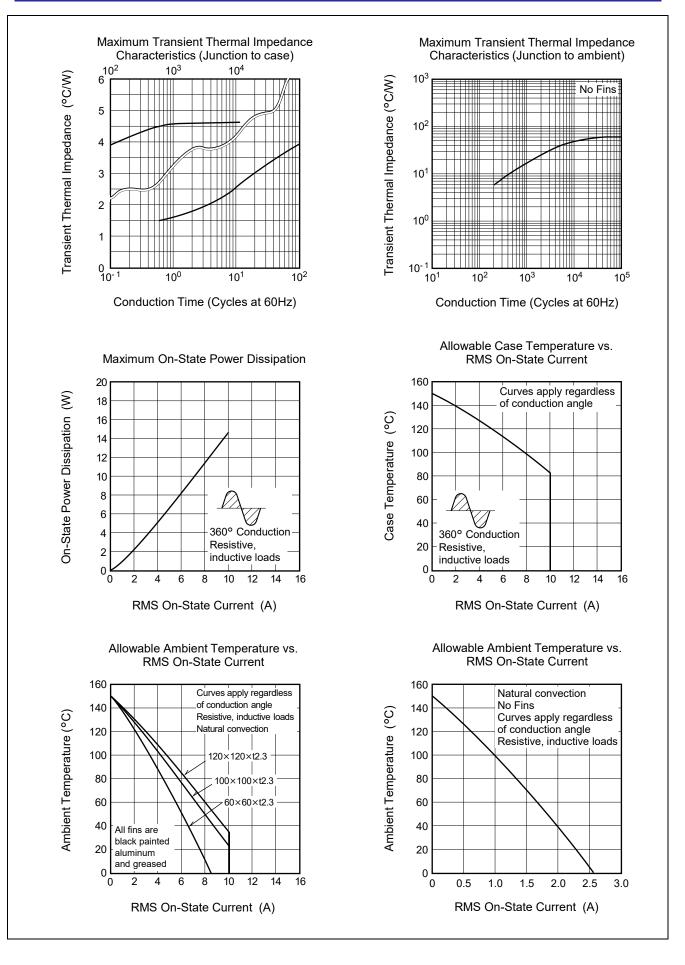
Test conditions	Commutating voltage and current waveforms (inductive load)
<ol> <li>Junction temperature Tj = 125°C</li> <li>Rate of decay of on-state commutating current (di/dt)c = -5 A/ms</li> <li>Peak off-state voltage V<sub>D</sub> = 400 V</li> </ol>	Supply Voltage Main Current Main Voltage (dv/dt)c VD



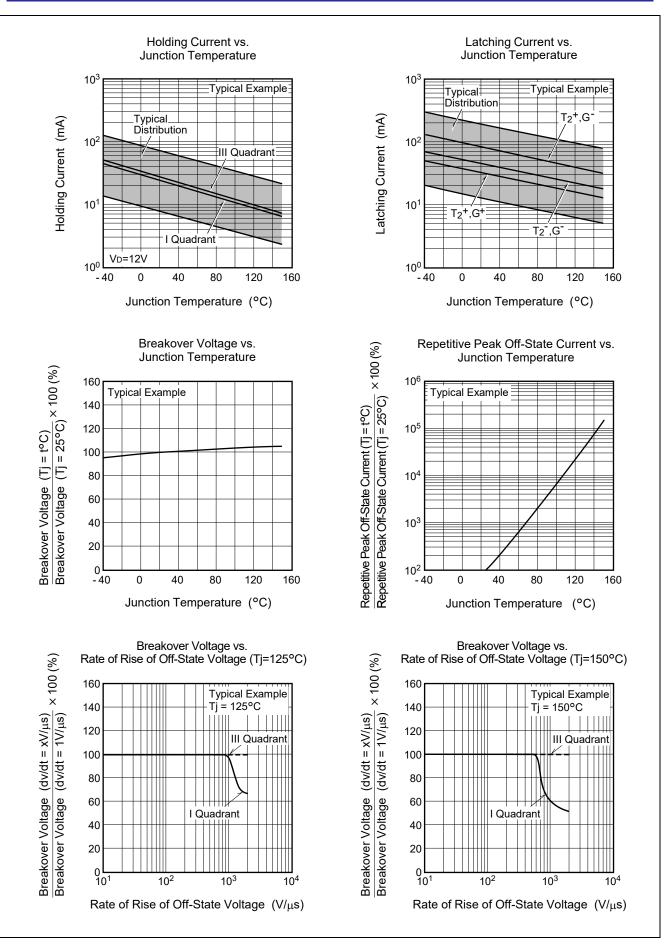
# **Performance Curves**



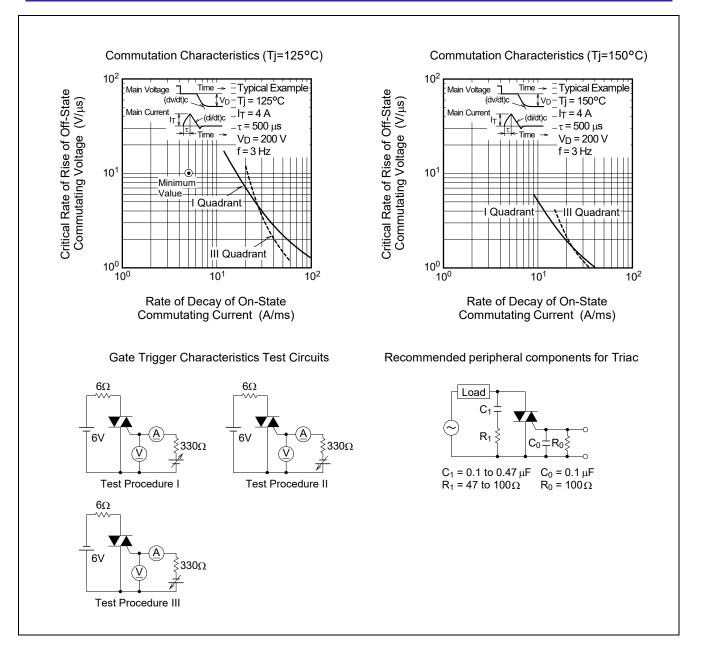




RENESAS



RENESAS



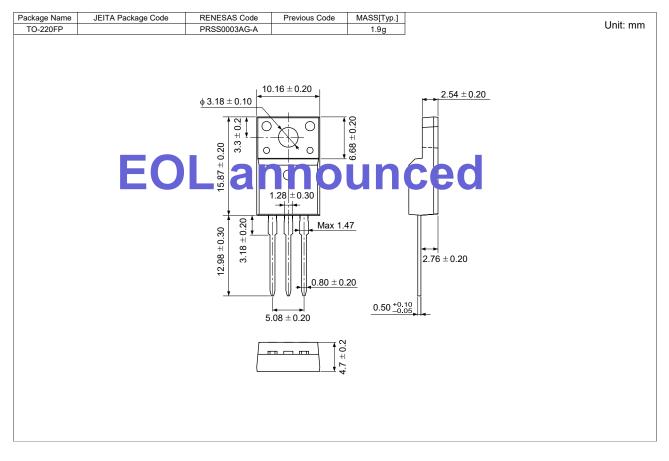
# Package Dimensions

#### Ordering code: #BG0

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
- PRSS0003AF		TO-220FPA	1.65
	2	.7±0.2	Unit: mm
	3.2±0.2		

#### **Package Dimensions**

#### Ordering code: #BB0 <EOL announced>



# **Ordering Information**

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR10FM-12LC#BG0	TO-220FPA	50 pcs./ tube	Straight type	Mass Production
BCR10FM-12LCDD#BG0	TO-220FPA	50 pcs./ tube	□□:Lead form type	
BCR10FM-12LC#BB0	TO-220FP	50 pcs./ tube	Straight type	EOL announced
BCR10FM-12LCDD#BB0	TO-220FP	50 pcs./ tube	□□:Lead form type	

Notes: 6. Please confirm the specification about the shipping in detail.

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